



DMTH4004SK3

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Qg Typ	I _D T _C = +25°C (Note 9)	
40V	3.2mΩ @ V _{GS} = 10V	68.6nC	100A	

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- **Engine Management Systems**
- **Body Control Electronics**
- **DC/DC** Converters

Features

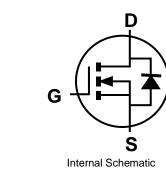
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.33 grams (Approximate)



Top View



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH4004SK3-13	TO252	2,500/Tape & Reel

S

D

D

Top View

Pin Out

G

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. Notes:

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



DII = Manufacturer's Marking T4004S = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 14 = 2014) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 6)	T _C = +25°C (Note 9)	I _D	100	А
	$T_{\rm C} = +100^{\circ}{\rm C}$		100	
Maximum Body Diode Forward Current (Note 6)	ls	100	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	160	A	
Avalanche Current, L=0.2mH	I _{AS}	40	A	
Avalanche Energy, L=0.2mH		E _{AS}	160	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.9	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	38	°C/W
Total Power Dissipation (Note 6) $T_{C} = +25^{\circ}C$		PD	180	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	0.8	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

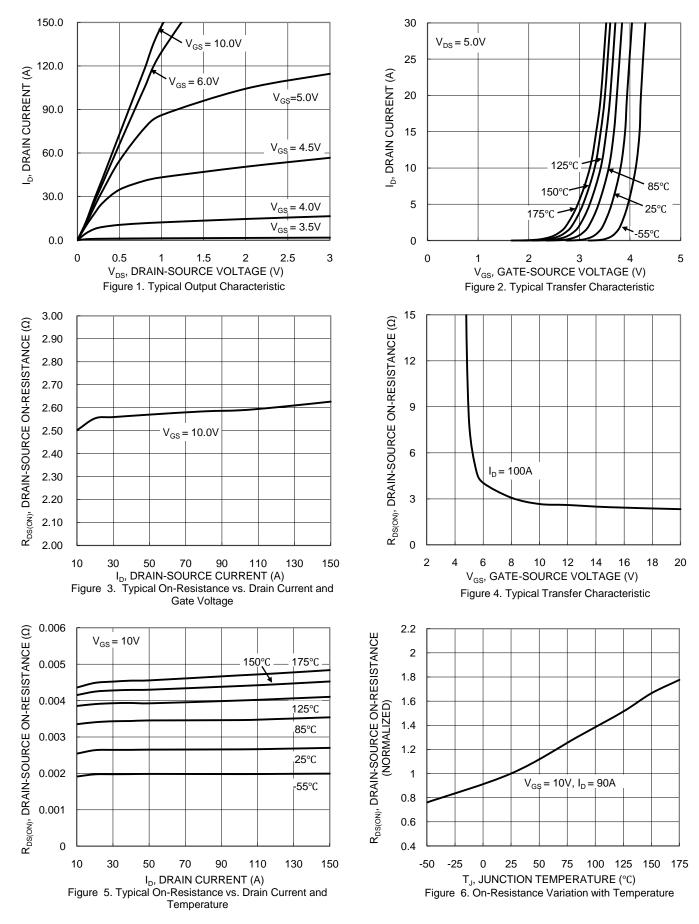
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40		_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2		4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		2.6	3.2	mΩ	$V_{GS} = 10V, I_D = 90A$	
Diode Forward Voltage	V _{SD}		0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		4305	—		$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$	
Output Capacitance	Coss		1441	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	102	_			
Gate Resistance	R _G		0.77	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	68.6	—			
Gate-Source Charge	Q _{gs}	_	16.8	_	nC	$V_{DS} = 20V, I_D = 90A,$	
Gate-Drain Charge	Q _{gd}	_	14.2	—		$V_{GS} = 10V$	
Turn-On Delay Time	t _{D(ON)}	_	9.5	_		V _{DD} = 20V, V _{GS} = 10V,	
Turn-On Rise Time	t _R	_	6.7	_	ns		
Turn-Off Delay Time	t _{D(OFF)}		26.4		115	$I_D = 90A, R_G = 3.5\Omega$	
Turn-Off Fall Time	t _F		8.1				
Body Diode Reverse Recovery Time	t _{RR}		52.4		ns		
Body Diode Reverse Recovery Charge	Q _{RR}		78.2		nC	I _F = 50A, di/dt = 100A/µs	

Notes: 5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state.
6. Thermal resistance from junction to solder point (on the exposed drain pin).
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.
9. Package imited.

9. Package limited.



DMTH4004SK3

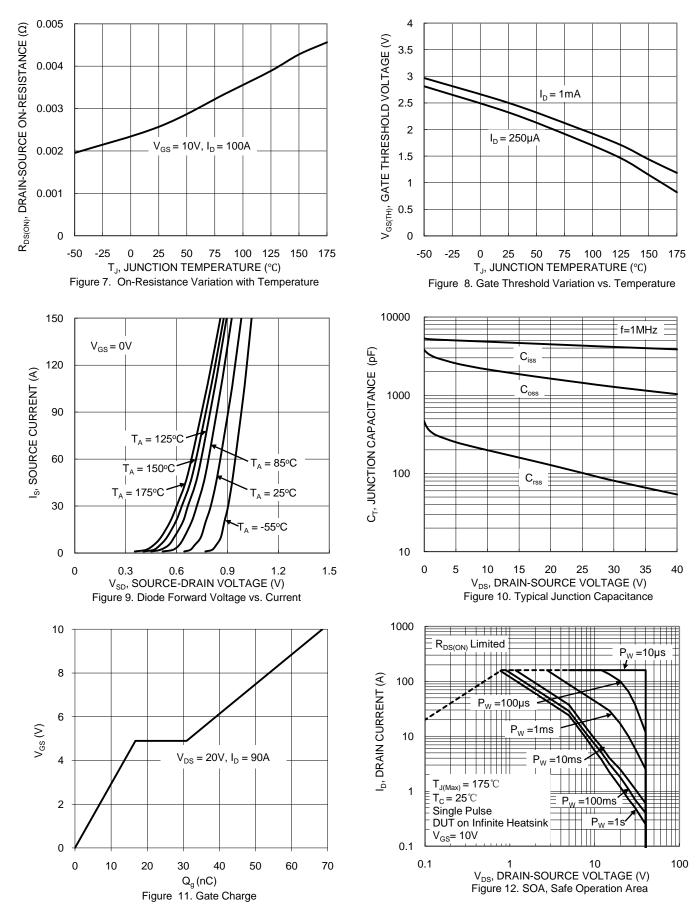


NEW PRODUCT

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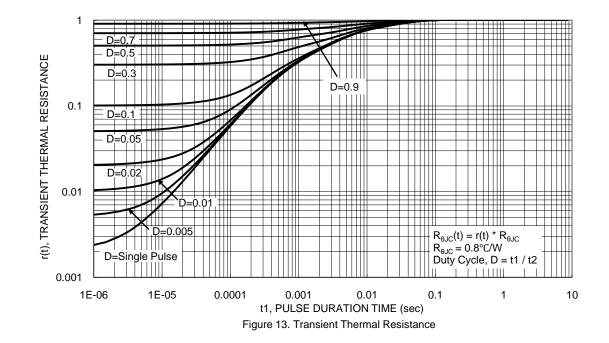
DMTH4004SK3



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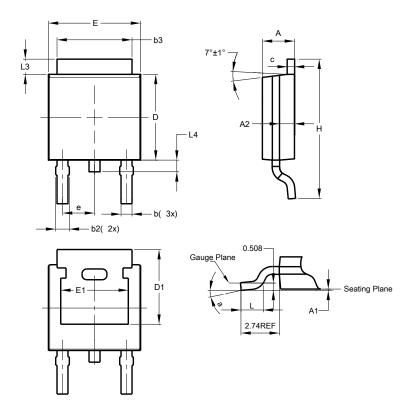






Package Outline Dimensions

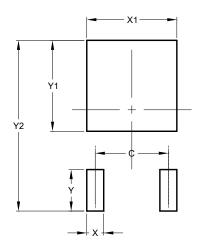
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
A1	0.00	0.13	0.08			
A2	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
С	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Е	6.45	6.70	6.58			
E1	4.32	-	-			
Н	9.40	10.41	9.91			
L	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		



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